Vishay Semiconductors



Silicon NPN Phototransistor, RoHS Compliant



DESCRIPTION

BPW77 is a silicon NPN phototransistor with high radiant sensitivity in hermetically sealed TO-18 package with base terminal and glass lens. It is sensitive to visible and near infrared radiation.

FEATURES

Package type: leadedPackage form: TO-18

• Dimensions (in mm): Ø 4.7

High photo sensitivity

· High radiant sensitivity

• Suitable for visible and near infrared radiation

Fast response times

• Angle of half sensitivity: $\varphi = \pm 10^{\circ}$

· Base terminal connected

· Hermetically sealed package

 Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

APPLICATIONS

· Detector in electronic control and drive circuits

PRODUCT SUMMARY						
COMPONENT	I _{ca} (mA)	φ (deg)	λ _{0.1} (nm)			
BPW77NA	7.5 to 15	± 10	450 to 1080			
BPW77NB	> 10	± 10	450 to 1080			

Note

Test condition see table "Basic Characteristics"

ORDERING INFORMATION						
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM			
BPW77NA	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18			
BPW77NB	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18			

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Collector base voltage		V _{CBO}	80	V	
Collector emitter voltage		V _{CEO}	70	V	
Emitter base voltage		V _{EBO}	5	V	
Collector current		Ic	50	mA	
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA	
Total power dissipation	T _{amb} ≤ 25 °C	P _V	250	mW	
Junction temperature		Tj	125	°C	
Operating temperature range		T _{amb}	- 40 to + 125	°C	
Storage temperature range		T _{stg}	- 40 to + 125	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	400	K/W	
Thermal resistance junction/gase		R _{thJC}	150	K/W	

Note

 T_{amb} = 25 °C, unless otherwise specified





ROHS



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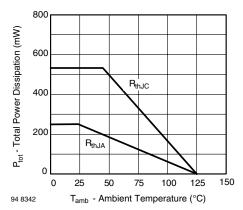


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Collector emitter breakdown voltage	I _C = 1 mA	V _{(BR)CEO}	70			V	
Collector emitter dark current	V _{CE} = 20 V, E = 0	I _{CEO}		1	100	nA	
Collector emitter capacitance	$V_{CE} = 5 \text{ V}, f = 1 \text{ MHz}, E = 0$	C _{CEO}		6		pF	
Angle of half sensitivity		φ		± 10		deg	
Wavelength of peak sensitivity		λ_{p}		850		nm	
Range of spectral bandwidth		λ _{0.1}		450 to 1080		nm	
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $I_C = 1 \text{ mA}$	V _{CEsat}		0.15	0.3	V	
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t _{on}		6		μs	
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t _{off}		5		μs	
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f _c		110		kHz	

Note

T_{amb} = 25 °C, unless otherwise specified

TYPE DEDICATED CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$	BPW77NA	I _{ca}	7.5		15	mA
	$V_{CE} = 5 V$	BPW77NB	I _{ca}	10			mA

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

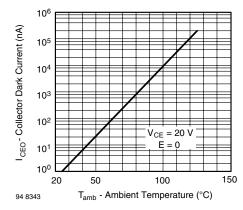


Fig. 2 - Collector Dark Current vs. Ambient Temperature

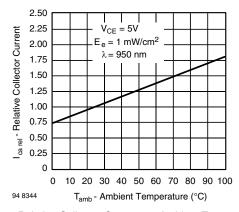


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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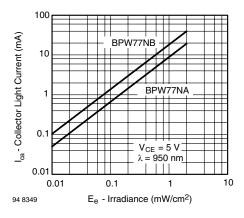


Fig. 4 - Collector Light Current vs. Irradiance

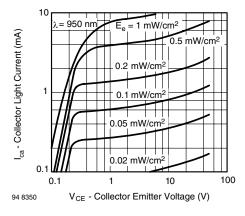


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

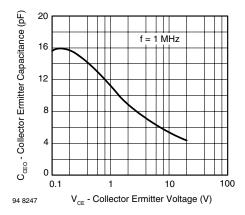


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

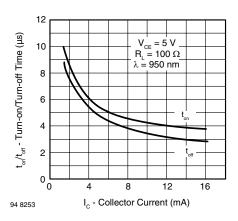


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

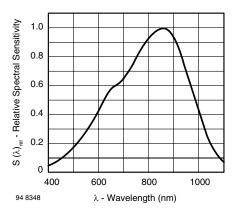


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

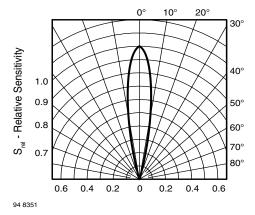
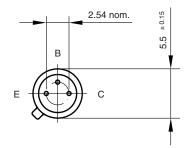


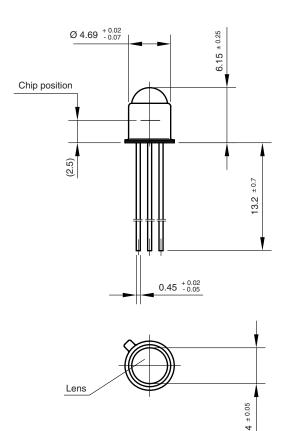
Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

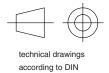


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PACKAGE DIMENSIONS in millimeters







specifications

Drawing-No.: 6.503-5023.01-4

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